NSN 5961-01-216-2049



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-216-2049 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pnp **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 collector to emitter voltage/static/base open and 15.0 collector to base voltage/static/emitter open and 4.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 50.00 milliamperes collector current, dc **Power Rating Per Characteristic:** 300.0 milliwatts collector power dissipation **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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